Excitability of excitons and biexcitons in a ring cavity

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We discuss the excitable behavior of excitons and biexcitons in a nonlinear optical ring cavity. The nonlinearity is due to the process of the creation of biexcitons by photon-assisted conversion of excitons. In the bifurcation analysis a region where a saddle point is close to an equilibrium has been found. In this region the system shows excitability. It is shown that the mechanism of the excitable behavior of excitons and biexcitons in a ring cavity is different from that of two-level atoms in the same system. The possible applications of an excitable ring cavity are discussed.

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I. INTRODUCTION

Excitability is quite an old concept, which is particularly well known in biology [1–3] where it is used to explain a number of phenomena including neural communication by nerve cells via electrical signalling. A system is said to be excitable if a stimulus below some threshold value produces a negligible response while one above the threshold results in a substantial response which is essentially independent of the size of the stimulus. Excitability also occurs in chemistry [4], physics, and engineering [5–8]. Some general concepts of excitability in optics and associated models have been discussed in Ref. [9]. Excitability in optics is of great interest because of its prospects for applications in optoelectronics devices, primarily for optical switching, clock recovery, pulse reshaping, tuneable pulses, and for generating a coherent resonant output pulse in communication networks.

Reference [5] has proposed and discussed excitability in a ring cavity containing a homogeneously broadened two-level nonlinear medium. Excitability in this system occurs in the small parameter window close to a bistable operating region, and originates from the combined dynamical effects of nonlinear intracavity field saturation and temperature-dependent absorption in the medium on two different times scales. The origin of the excitability is similar to that in the FitzHugh-Nagumo model. More recently, excitability has been predicted in lasers with a saturable absorber [6], with delayed optical feedback [7] and with an integrated dispersive reflector [8]. In Ref. [6] it is shown that a laser with a saturable absorber displays excitability just below threshold. The analytical expression for the excitability threshold was obtained by considering the slow-fast nature of the system. Under the influence of optical noise the laser displays coherence resonance. Excitability in this system is due to an attractor close to a saddle point. This is the second type of mechanism leading to excitability that is found in literature.

In this paper, we have studied the excitability of excitons and biexcitons in a nonlinear optical ring cavity. The optical nonlinearity is considered to be due to the creation of biexcitons by the interaction of excitons and photons. The relaxation times of excitons and biexcitons are very short, being of the order of picoseconds, which means that mechanisms based on them are suitable for use in optoelectronic devices where ultrafast response is required. Biexcitons can be readily created in wide gap semiconductors such as CuCl, CuBr, and CdS where the electron-hole interaction is strong. But different mechanisms for their formation in bulk semiconductors have been proposed in the literature. The giant oscillator strength model which has been proposed by Hamamura, and Gogolin and Rashba [10,11] has been successfully applied to explain many biexciton-related optical processes in bulk semiconductors. More recently, Ivanov, Haug, and Keldysh have proposed a bipolariton model of biexcitons [12]. It has been shown [13–15] that both microscopic models can be used to form the basis of theoretical description of the phenomena of optical bistability, self pulsation, and chaos. Comparison with high-precision experiments supports the view [12,16] that the bipolariton model gives the better description of the microscopic processes, particularly in low-dimensional systems. Nevertheless, the giant oscillator model has had considerable success in bulk semiconductors and provides a basis for a model of excitability which is substantially more tractable than what is currently possible with the bipolariton theory.

The paper is structured as follows. In Sec. II we present the model equations for excitons, biexcitons, and photons in the ring cavity and the bifurcation analysis. Section III demonstrates excitable behavior in the system and the possible applications of excitability are discussed. The conclusions are given in Sec. IV.

II. DYNAMICS

A. Equations

For simplicity we use the three-level model which has been previously applied to a CuCl crystal, where there is convincing experimental evidence of the existence of biexcitons. In a CuCl crystal the biexciton bond energy is of the order of 40 meV and the exciton absorption band and the M band of biexciton recombination are well separated from each other. We study the simultaneous action of two independent optical pulses. The photons of the first pulse with energy \(h \omega_1 = E_{ex} - I_{ex}\) are in resonance with a transition in the exciton spectral range. The photons of the second pulse, which
cause exciton-biexciton conversion, have an energy \( h \omega_2 = E_g - E_{\text{ex}} - E_{\text{biex}} \) and are in resonance with the region of the fluorescence band of a CuCl crystal. \( E_g \) is the band gap, \( E_{\text{ex}} \) and \( E_{\text{biex}} \) are the exciton and biexciton binding energies, respectively.

The full Hamiltonian of the system consists of a sum of the Hamiltonians for free excitons, biexcitons, and the electromagnetic field, and the interaction Hamiltonian, which has the form

\[
H_{\text{int}} = -h g (a E_i^+ - a^\dagger E_i^-) - h G (a E_j^+ b - b^\dagger E_j^+),
\]

where \( a^\dagger \) and \( b^\dagger \) are the creation operators of an exciton and a biexciton, respectively, and \( E_j^+ \) is the positive frequency component of the electric field of electromagnetic wave of the \( j \)th pulse \( (j = 1, 2) \). \( g \) is the constant of the exciton-photon interaction and \( G \) is the exciton-biexciton conversion coefficient. This Hamiltonian treats excitons and biexcitons as independent Bose quasiparticles.

The macroscopic equations for the positive-frequency field components \( E_j^+ \) and for the exciton (A) and biexciton (B) amplitudes [17], neglecting spatial dispersion have the form

\[
c_i^2 \frac{\partial^2 E_j^+}{\partial z^2} - \frac{\partial^2 E_j^+}{\partial t^2} = 4 \pi \hbar g \frac{\partial^2 A}{\partial t^2}, \tag{1}
\]

\[
c_i^2 \frac{\partial^2 E_2^+}{\partial z^2} - \frac{\partial^2 E_2^+}{\partial t^2} = 4 \pi \hbar g G \frac{\partial^2 (A^+ B)}{\partial t^2}, \tag{2}
\]

\[
i \frac{dA}{dt} = \omega_{\text{ex}} A - g E_1^+ - g G E_i^2 - i \gamma_{\text{ex}} A, \tag{3}
\]

\[
i \frac{dB}{dt} = \omega_{\text{biex}} B - g G E_2^+ A - i \gamma_{\text{biex}} B, \tag{4}
\]

where \( c_j \) is the velocity of \( j \)th field propagation in the medium, \( \hbar \omega_{\text{ex}} (\hbar \omega_{\text{biex}}) \) is the energy of exciton (biexciton) formation and \( \gamma_{\text{ex}} \) and \( \gamma_{\text{biex}} \) are the inverse coherence lifetimes of excitons and biexcitons, respectively. Although the lifetimes can be considered as phenomenological parameters, Eqs. (3) and (4) can be derived rigorously using the quantum theory of fluctuations [18] (see also [19]).

In the subsequent analysis we use the slowly varying envelope approximation [20,21]. That is, we represent the solution of Eqs. (1)–(4) in the form of relatively slowly varying envelopes \( e_j^+, e_2^+, \tilde{A}, \tilde{B} \), and rapidly oscillating components with frequencies \( \omega_1 \) and \( \omega_2 \) with corresponding wave-vectors \( \mathbf{k}_1 \) and \( \mathbf{k}_2 \)

\[
E_1^+ = e_1^+(z, t) \exp(-i \omega_1 t + ik_1 z),
\]

\[
E_2^+ = e_2^+(z, t) \exp(-i \omega_2 t + ik_2 z),
\]

\[
A = \tilde{A}(z, t) \exp(-i \omega_1 t + ik_1 z),
\]

\[
B = \tilde{B}(z, t) \exp(-i (\omega_1 + \omega_2) t + i(k_1 + k_2) z). \tag{5}
\]

We describe the phenomenon of excitability of excitons and biexcitons in the ring cavity shown schematically in Fig. 1. The input and output mirrors have reflectivity \( R = 1 - T \) and are separated by distance \( L \). The other corner mirrors in the ring have a reflectivity of unity. The boundary conditions for the ring cavity are

\[
e_{T,j}(t) = \sqrt{T} e_j^+(L, t),
\]

\[
e_j^+(0, t) = \sqrt{T} e_{T,j} + \text{Re} e_j^+(L, t - \Delta t), \tag{6}
\]

where \( \Delta t = (L_r - L)/c \) is the retardation time introduced by the feedback, \( L_r = 2(L + l) \) is the length of ring cavity, \( c \) is the velocity of light in vacuum, \( \beta_0 \) is the cavity-laser phase detuning.

For integration of Eqs. (1) and (2) we use the mean-field theory [22,23] which corresponds mathematically to the replacement of \( \int E(z) dz \) by \( [E(L) - E(0)]L \). In this approximation with the trial solutions (5) and boundary condition (6), Eqs. (1)–(4) become in dimensionless form

\[
\frac{dX_1}{d\tau} = \sigma_1 (-X_1 + 2C_1 U + Y_1), \tag{7}
\]

\[
\frac{dX_2}{d\tau} = \sigma_2 (-X_2 - 2C_2 U V + Y_2), \tag{8}
\]

\[
\frac{dU}{d\tau} = -dU - d(X_1 + X_2 V), \tag{9}
\]

\[
\frac{dV}{d\tau} = -V + X_2 U, \tag{10}
\]

where \( Y_j = e_j g G / \sqrt{\gamma_{\text{ex}} \gamma_{\text{biex}}} \) and \( X_j = e_j g G / \sqrt{\gamma_{\text{ex}} \gamma_{\text{biex}}} \) are the normalized field amplitudes, while \( U = i \tilde{A} \sqrt{\gamma_{\text{biex}}} / \sqrt{\gamma_{\text{ex}}} G \) and \( V = \tilde{B} G \) are the normalized exciton and biexciton amplitudes, respectively. Here we have used the dimensionless time \( \tau = \tau_{\text{biex}} \) (for a typical value of \( \gamma_{\text{biex}} = 10^{13} \text{ s}^{-1} \), \( \tau = 1 \) corresponds to a time of 1 ps) and the following notation: \( d = \gamma_{\text{ex}} / \gamma_{\text{biex}} \) is the decay rate of an exciton relative to that of a biexciton, \( \sigma_j = c_j R L / \gamma_{\text{biex}} \) is the damping of the electric-field amplitude in the cavity and...
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FIG. 2. The bifurcation diagram for $Y_1=10$, $\sigma=0.1$, $C_1=C_2=5$, and $d=0.1$. Thin solid: stable stationary states. Thin dotted: unstable stationary states. Thick solid: stable periodic solutions. Thick dotted: unstable periodic solutions. The square denotes a Hopf bifurcation. The rhombuses mark saddle-node bifurcations. FN shows the transition from unstable focus to unstable node, and NF the transition from stable node to stable focus. Point G marks the operating point. The inset: sketch of phase portrait for region $Y_3(S_1) - Y_3(S_2)$ in the plane $X_3-X_1$.

$C_j = \alpha_j L/4T$ with $\alpha_j = 4 \pi h g/\gamma e c_j$. Close to a cavity resonance $e^{i\beta_0} = 1 + i \beta_0$ and we consider only the real part of amplitudes.

Equations (7)–(10) completely describe the evolution of excitons and biexcitons in the ring cavity in the model used, and are the basis of the analysis that follows.

B. Bifurcation diagrams

In this section, we discuss the ring cavity dynamics of excitons and biexcitons in terms of bifurcation diagrams. The calculations were carried out with the software package AUTO97 [24] for continuation and bifurcation problems in ordinary differential equations. Specifically, we applied a numerical bifurcation analysis to Eqs. (7)–(10). The initial conditions $(X_1; X_2; U; V) = [Y_1/(1+2C_1); 0; X_1; 0]$ have been used, which correspond to the steady state with a constant pump so that there is a steady-state population of excitons. In particular, we consider the bifurcation diagram in the plane $X_2 - Y_2$ (output amplitude-input amplitude) with the amplitude of the input pulse $Y_2$ as the parameter to be varied (branching parameter). Figure 2 shows a typical example of the bifurcation diagram for the system. The parameters used are $\sigma_1 = \sigma_2 = \sigma = 0.1$, $C_1 = C_2 = 5$, $d = 0.1$, and $Y_1 = 10$. A thin continuous line represents stable stationary solutions, and unstable stationary solutions are indicated by a thin dotted line. A thick solid line represent a stable periodic solution. The unstable periodic solutions are marked by thick dotted line. It is well known that a Hopf bifurcation point (marked by the square) connects the stationary solution with the periodic solution. It is apparent in Fig. 2 that the periodic branch turns back and loses stability. This kind of bifurcation is described as subcritical. When $Y_2$ is increased from $Y_3(0)$ to $Y_2(H)$, $X_2$ jumps to a large amplitude periodic orbit as hard generation of a limit cycle occurs. When $Y_2$ is reduced from $Y_2(T)$ a discontinuity occurs again at $Y_2(P)$ with a jump from a large value to equilibrium. In the region $OP$ at any given $Y_2$, there is only one equilibrium state, a stable focus which attracts all orbits. A stable periodic orbit, a stable equilibrium, and an unstable periodic orbit coexist in the domain $Y_2(P) - Y_2(H)$. In this interval we have a hysteresis loop of periodic solutions. Moving from $H$ to $T$, a stable limit cycle is the only attractor. The periodic branch ends at $T$ where a homoclinic orbit is present and the periods of periodic orbits tends to $\infty$. The nature of self-pulsations in the region $HT$ for different parameters has been discussed in [14].

Two saddle-point bifurcations are marked by rhombuses in Fig. 2. A stability analysis of Eqs. (7)–(10) shows that between $H$ and $S_1$ there is a transition from an unstable focus to an unstable node at point $FN$. On the other hand, at point $NF$ we detect the transition from a stable node to a stable focus.

Now we discuss in more detail the region between the saddle-node bifurcations $S_1$ and $S_2$. It is known that the existence of a saddle point close to an attractor is the requirement for excitability. The inset in Fig. 2 shows a sketch of the phase portraits in the plane $X_3-X_1$ in this region. There is an attractor (stable node in nonlinear case), a saddle, and an unstable focus for a fixed value of amplitude of the input pulse $Y_2$. A sufficiently large perturbation can bring the system below the stable manifold (separatrix) of the saddle point so that the system makes a big loop around the unstable focus. In this region the system shows excitability with a mechanism similar to that in Ref. [6].

III. EXCITABILITY

A. Demonstration of excitability and discussion

A system is excitable if it exhibit the following properties [6,7]:

(i) the existence of a threshold above which an excitation can occur,

(ii) above threshold the form of the response independent of the perturbation magnitude,

(iii) a refractory period exists.

As noted in the previous section, our system is excitable in the region $S_1-S_2$, and we now discuss the dynamics of this phenomenon in more detail. We choose suitable values of the parameters to achieve excitability. The criterion for the existence of hysteresis of stationary solutions is the inequality $Y_1 > \sqrt{2(1+2C_1)}/C_2$ [14]. The parameters $\sigma$ and $d$ influence the dynamics of the system and we choose $d=0.1$ since we consider the relaxation time of excitons to be one-order smaller than that of biexcitons. In this case for any $\sigma < 0.1$ the behavior of the system is similar to that sketched in Fig. 2. We choose the operating point close to the saddle-point $S_1$. First we consider the response of the system to a
rectangular input pulse of amplitude $Y_0$. The initial conditions correspond to point $G$ in Fig. 2, for which $Y_2=8.8$. For this point we found the threshold perturbation value $Y_0 = 0.695$. Figure 3(a) shows the response of the system to a perturbation of amplitude $Y_0=0.69$, which is below threshold. When the amplitude of the perturbation is increased to $Y_0=0.7$ which is above the threshold the system starts to exhibit excitable behavior with a significant pulse-like reduction in $X_2$ as shown in Fig. 3(b). To study the trend of trajectories in the phase space, let us assume that the duration $\delta t$ of applied stimulus $Y_0$ is much shorter than the characteristic time of the system. In that case the stimulus affects only the amplitude $X_2$ and the phase trajectories start at $(X_1, X_2, U, V) = (X_1^0, X_2^0, A^0, B^0)$. Figure 3(b) shows the trajectories in the plane $X_2-X_1$, for a stimulus below threshold-trajectory $A$ ($\delta X_2 = 1.05$), and above threshold-trajectory $B$ ($\delta X_2 = 1.06$). Trajectory $A$ turns back to equilibrium in contrast to trajectory $B$ which makes a big loop around the unstable focus. The position of trajectory $A$ is situated higher than the stable manifold of the saddle (see inset of Fig. 2) while the starting point of trajectory $B$ is down that stable manifold. The threshold is situated along the stable manifold. The dependence of excitable threshold $X_2^{\text{th}}$ on $Y_2$ is shown in the inset of Fig. 4. With the increase of $Y_2$ from $Y_2(S_1)$, the saddle point moves down and the amplitude of threshold increases meaning that the system becomes less excitable. Figure 4 shows the dependence of the value of the minimum in the response of the transmitted field $X_2^{\text{min}}$ on the amplitude of the perturbation $Y_0$ for two different values of $Y_2$. It shows that near $S_1$ we need only a small perturbation amplitude in contrast to point $S_2$, where a higher-perturbation amplitude is necessary to achieve excitability and also the jump at the threshold is less pronounced. However above threshold the response is essentially independent of perturbation magnitude, and the second characteristic of excitability is fulfilled.

Finally we give an example to confirm the existence of a refractory period. Two pulses with amplitudes above threshold are applied to the system. Figure 5(a) shows the response of the system when the delay time between pulses is $\tau_d = 25$. It does not differ from the response to a single pulse (see Fig. 3(b) for comparison). When the second pulse is applied with delay $\tau_d = 50$ there is a small reaction to it. After increasing $\tau_d$ further to 75 we can distinguish a clear response to the second pulse. The system is able to make a distinct and essentially identical response to both pulses when $\tau_d > 100$. We conclude that for this set of parameters the refractory time is the order of $45\tau$.

### B. Applications of excitability

One motivation for research into excitability is its possible application in all-optical signal processing. This section shows some examples of the possible applications of excitability. As an optical limiter, the excitable element could serve to limit or suppress the noise level and any pulses below threshold. The excitable element can also be used as a logic element. For a subthreshold input we have zero output, but for an input above threshold the output is a one signal.

Consider a sequences of pulses ($\tau = 15$ width) with different amplitudes and different delay time between pulses, such as the case shown in Fig. 6(a). We observe a big response only to input pulses which exceed the threshold. Other pulses cause negligible response and should be recognized as zero.
For CuCl reasonable material parameter values are: binding energy of biexcitons is 40 meV, \( \gamma_{\text{ex}} = 0.03 \text{ meV} \), \( \gamma_{\text{biexc}} = 0.3 \text{ meV} \), \( \hbar \omega = 0.3 \text{ eV/} \text{cm}^{1/2} \text{ V} \), \( G = 1.25 \times 10^8 \text{ cm}^{1/2} \). For a cavity with \( L = 3 \) \( \mu \text{m} \) and \( T = 0.01 \), the intensities \( I_1 = |E_1|^2 = 10 \text{ kW/cm}^2 \) and \( I_2 = |E_2|^2 = 89 \text{ kW/cm}^2 \) ensure that the cavity is in the excitable region. On the basis of our investigations and parameter estimations we conclude that it should be possible to observe excitability in a system of excitons and biexcitons in a ring cavity.

IV. CONCLUSIONS

We have shown that excitability of excitons and biexcitons in a ring cavity can occur. In the bifurcation analysis it is found that the excitable region is situated in the domain between pulses (a) \( \tau_d = 25 \), (b) \( \tau_d = 50 \), (c) \( \tau_d = 75 \), and (d) \( \tau_d = 125 \) (\( \tau_d = \gamma_{\text{biexc}} \)). The other parameters are \( Y_1 = 10 \), \( \sigma_1 = \sigma_2 = 0.1 \), \( C_1 = C_2 = 5 \), \( d = 0.1 \), and \( Y_2 = 8.8 \).

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